

CLAIMS:

-
1. An electro-optical device having an ITO (indium tin oxide) layer and a SiN layer near the ITO layer, characterized in that an intermediate layer of silicon oxide is provided between the ITO layer and the SiN layer.
2. An electro-optical device as claimed in claim 1, characterized in that the electro-optical device is a fingerprint sensor.
-
3. An electro-optical device as claimed in claim 1, characterized in that the electro-optical device is an X-ray image sensor.

add A>